### VS-8TQ060-M3, VS-8TQ080-M3, VS-8TQ100-M3

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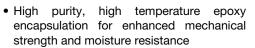
## **High Performance Schottky Rectifier, 8 A**



| PRIMARY CHARACTERISTICS          |                   |  |  |  |  |  |  |
|----------------------------------|-------------------|--|--|--|--|--|--|
| I <sub>F(AV)</sub>               | 8 A               |  |  |  |  |  |  |
| V <sub>R</sub>                   | 60 V, 80 V, 100 V |  |  |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.58 V            |  |  |  |  |  |  |
| I <sub>RM</sub> max.             | 7 mA at 125 °C    |  |  |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C            |  |  |  |  |  |  |
| E <sub>AS</sub>                  | 7.5 mJ            |  |  |  |  |  |  |
| Package                          | 2L TO-220AC       |  |  |  |  |  |  |
| Circuit configuration            | Single            |  |  |  |  |  |  |

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |   |             |    |  |  |  |  |
|-----------------------------------|---|-------------|----|--|--|--|--|
| SYMBOL CHARACTERISTICS VALUES     |   |             |    |  |  |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                        | 8           | Α  |  |  |  |  |
| V <sub>RRM</sub>                  | Range                                       | 60 to 100   | V  |  |  |  |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 μs sine                  | 850         | Α  |  |  |  |  |
| V <sub>F</sub>                    | 8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.58        | V  |  |  |  |  |
| T <sub>J</sub>                    | Range                                       | -55 to +175 | °C |  |  |  |  |

| VOLTAGE RATINGS   |                  |    |    |     |   |  |  |  |
|---|------------------|----|----|-----|---|--|--|--|
| PARAMETER SYMBOL VS-8TQ060-M3 VS-8TQ080-M3 VS-8TQ100-M3 UNITS |                  |    |    |     |   |  |  |  |
| Maximum DC reverse voltage                                    | $V_R$            | 60 | 80 | 100 | W |  |  |  |
| Maximum working peak reverse voltage                          | V <sub>RWM</sub> | 00 | 00 | 100 | V |  |  |  |

| ABSOLUTE MAXIMUM RATINGS                    |                    |   |   |       |    |  |  |  |
|---|--------------------|---|---|-------|----|--|--|--|
| PARAMETER                                   | SYMBOL             | TEST COND   | VALUES  | UNITS |    |  |  |  |
| Maximum average forward current, see fig. 5 | I <sub>F(AV)</sub> | 50 % duty cycle at T <sub>C</sub> = 157 °C  | 8   | А     |    |  |  |  |
| Maximum peak one cycle non-repetitive       | I <sub>FSM</sub>   | 5 μs sine or 3 μs rect. pulse   | Following any rated load condition and with rated | 850   | A  |  |  |  |
| surge current, see fig. 7                   |                    | 10 ms sine or 6 ms rect. pulse  | V <sub>RRM</sub> applied                          | 230   |    |  |  |  |
| Non-repetitive avalanche energy             | E <sub>AS</sub>    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.50 A, L = 60 mH   |   | 7.50  | mJ |  |  |  |
| Repetitive avalanche current                | I <sub>AR</sub>    | Current decaying linearly to zero in 1 $\mu$ s<br>Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical |   | 0.50  | Α  |  |  |  |



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| ELECTRICAL SPECIFICATIONS                  |                                |   |                                       |       |    |  |  |  |
|--|--------------------------------|---|---------------------------------------|-------|----|--|--|--|
| PARAMETER                                  | SYMBOL                         | TEST CO   | VALUES                                | UNITS |    |  |  |  |
| Maximum forward voltage drop<br>See fig. 1 |                                | 8 A   | T <sub>.1</sub> = 25 °C               | 0.72  | V  |  |  |  |
|  | V <sub>FM</sub> <sup>(1)</sup> | 16 A  | 1J=25 C                               | 0.88  |    |  |  |  |
|  |                                | 8 A   | T 105 °C                              | 0.58  |    |  |  |  |
|  |                                | 16 A  | - T <sub>J</sub> = 125 °C             | 0.69  | ı  |  |  |  |
| Maximum reverse leakage current            | ı (1)                          | T <sub>J</sub> = 25 °C                                | V <sub>B</sub> = rated V <sub>B</sub> | 0.55  | mΛ |  |  |  |
| See fig. 2                                 | I <sub>RM</sub> <sup>(1)</sup> | T <sub>J</sub> = 125 °C                               | v <sub>R</sub> = rated v <sub>R</sub> | 7     | mA |  |  |  |
| Maximum junction capacitance               | C <sub>T</sub>                 | V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range | 500                                   | pF    |    |  |  |  |
| Typical series inductance                  | L <sub>S</sub>                 | Measured lead to lead 5 m                             | 8                                     | nH    |    |  |  |  |
| Maximum voltage rate of change             | dV/dt                          | Rated V <sub>R</sub>                                  | 10 000                                | V/µs  |    |  |  |  |

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width  $<300~\mu s,$  duty cycle <2~%

| THERMAL - MECHANICAL SPECIFICATIONS            |         |                                   |                                       |             |            |  |  |  |
|--|---------|-----------------------------------|---------------------------------------|-------------|------------|--|--|--|
| PARAMETER                                      |         | SYMBOL                            | TEST CONDITIONS                       | VALUES      | UNITS      |  |  |  |
| Maximum junction and storage temperature range |         | T <sub>J</sub> , T <sub>Stg</sub> |                                       | -55 to +175 | °C         |  |  |  |
| Maximum thermal resistance, junction to case   |         | $R_{thJC}$                        | DC operation<br>See fig. 4            | 2.0         | - °C/W     |  |  |  |
| Typical thermal resistance, case to heatsink   |         | R <sub>thCS</sub>                 | Mounting surface, smooth, and greased | 0.50        |            |  |  |  |
| Approximate weight                             |         |                                   |                                       | 2           | g          |  |  |  |
| Approximate weight                             |         |                                   |                                       | 0.07        | OZ.        |  |  |  |
| Maunting targue                                | minimum |                                   |                                       | 6 (5)       | kgf · cm   |  |  |  |
| Mounting torque –                              | maximum |                                   |                                       | 12 (10)     | (lbf · in) |  |  |  |
| Marking device                                 |         |                                   |                                       | 8TQ060      |            |  |  |  |
|  |         |                                   | Case style 2L TO-220AC                | 8TQ080      |            |  |  |  |
|  |         |                                   |                                       | 8TC         | TQ100      |  |  |  |

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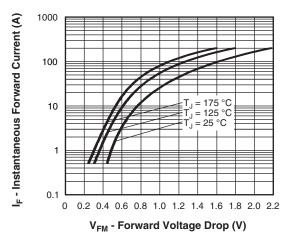


Fig. 1 - Maximum Forward Voltage Drop Characteristics

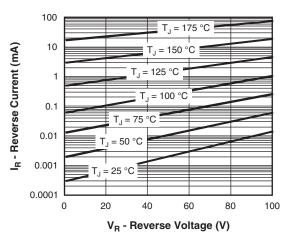


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage

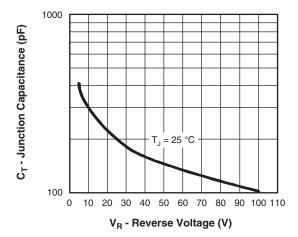


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

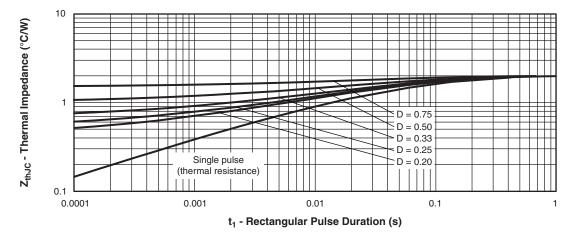


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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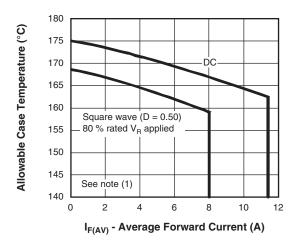


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

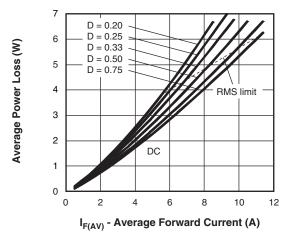


Fig. 6 - Forward Power Loss Characteristics

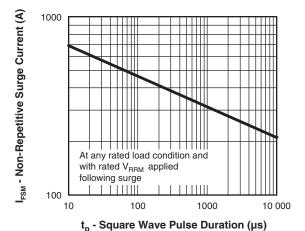


Fig. 7 - Maximum Non-Repetitive Surge Current

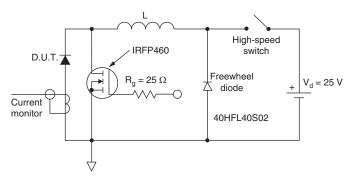


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

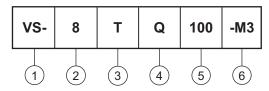
 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

# VS-8TQ060-M3, VS-8TQ080-M3, VS-8TQ100-M3

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#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

3 - Package:

T = TO-220

4 - Schottky "Q" series

060 = 60 V

5

- Voltage ratings

080 = 80 V100 = 100 V

6 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

| ORDERING INFORMATION (Example) |                  |                        |                         |  |  |  |  |  |  |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION   |  |  |  |  |  |  |
| VS-8TQ060-M3                   | 50               | 1000                   | Antistatic plastic tube |  |  |  |  |  |  |
| VS-8TQ080-M3                   | 50               | 1000                   | Antistatic plastic tube |  |  |  |  |  |  |
| VS-8TQ100-M3                   | 50               | 1000                   | Antistatic plastic tube |  |  |  |  |  |  |

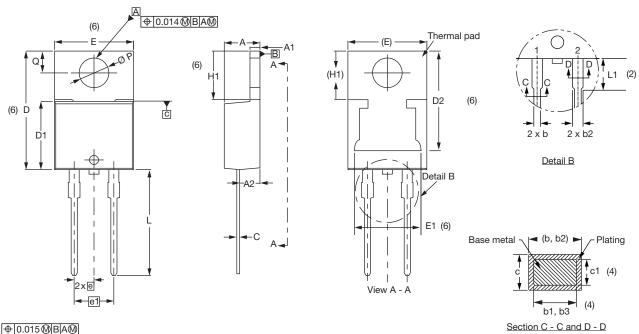
| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?96156 |  |  |  |  |  |
| Part marking information   | www.vishay.com/doc?95391 |  |  |  |  |  |
| SPICE model                | www.vishay.com/doc?96227 |  |  |  |  |  |

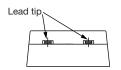


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### 2L TO-220AC

#### **DIMENSIONS** in millimeters and inches





Conforms to JEDEC® outline TO-220AC

| SYMBOL  | MILLIM | IETERS | INCHES |       | HES NOTES |       | SYMBOL  | MILLIN | IETERS | INC   | HES   | NOTES |
|---------|--------|--------|--------|-------|-----------|-------|---------|--------|--------|-------|-------|-------|
| STWIBOL | MIN.   | MAX.   | MIN.   | MAX.  | NOTES     | NOTES | STWIBOL | MIN.   | MAX.   | MIN.  | MAX.  | NOTES |
| Α       | 4.25   | 4.65   | 0.167  | 0.183 |           |       | D2      | 11.68  | 13.30  | 0.460 | 0.524 | 6, 7  |
| A1      | 1.14   | 1.40   | 0.045  | 0.055 |           |       | E       | 10.11  | 10.51  | 0.398 | 0.414 | 3, 6  |
| A2      | 2.50   | 2.92   | 0.098  | 0.115 |           |       | E1      | 6.86   | 8.89   | 0.270 | 0.350 | 6     |
| b       | 0.69   | 1.01   | 0.027  | 0.040 |           |       | е       | 2.41   | 2.67   | 0.095 | 0.105 |       |
| b1      | 0.38   | 0.97   | 0.015  | 0.038 | 4         |       | e1      | 4.88   | 5.28   | 0.192 | 0.208 |       |
| b2      | 1.20   | 1.73   | 0.047  | 0.068 |           |       | H1      | 6.09   | 6.48   | 0.240 | 0.255 | 6     |
| b3      | 1.14   | 1.73   | 0.045  | 0.068 | 4         |       | L       | 13.52  | 14.02  | 0.532 | 0.552 |       |
| С       | 0.36   | 0.61   | 0.014  | 0.024 |           |       | L1      | 3.32   | 3.82   | 0.131 | 0.150 | 2     |
| c1      | 0.36   | 0.56   | 0.014  | 0.022 | 4         |       | ØΡ      | 3.54   | 3.91   | 0.139 | 0.154 |       |
| D       | 14.85  | 15.35  | 0.585  | 0.604 | 3         |       | Q       | 2.60   | 3.00   | 0.102 | 0.118 |       |
| D1      | 8.38   | 9.02   | 0.330  | 0.355 |           |       |         | •      | •      |       |       |       |

#### **Notes**

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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